

# 1-BIT TO 4-BIT ADDRESS DRIVER WITH 3-STATE OUTPUTS

SCES085F – AUGUST 1996 – REVISED JUNE 1999

- **Member of the Texas Instruments Widebus™ Family**
- **EPIC™ (Enhanced-Performance Implanted CMOS) Submicron Process**
- **Output Ports Have Equivalent 26-Ω Series Resistors, So No External Resistors Are Required**
- **Latch-Up Performance Exceeds 250 mA Per JESD 17**
- **Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors**
- **Package Options Include Plastic 300-mil Shrink Small-Outline (DGG), Thin Shrink Small-Outline (DL), and Thin Very Small-Outline (DGV) Packages**

NOTE: For tape and reel order entry:  
The DGGR package is abbreviated to GR, and  
the DGV package is abbreviated to VR.

## description

This 1-bit to 4-bit address driver is designed for 1.65-V to 3.6-V  $V_{CC}$  operation.

The SN74ALVCH162344 is used in applications in which four separate memory locations must be addressed by a single address.

The outputs, which are designed to sink up to 12 mA, include equivalent 26-Ω resistors to reduce overshoot and undershoot.

To ensure the high-impedance state during power up or power down, the output enable ( $\overline{OE}$ ) inputs should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

The SN74ALVCH162344 is characterized for operation from  $-40^{\circ}\text{C}$  to  $85^{\circ}\text{C}$ .

## DGG, DGV, OR DL PACKAGE (TOP VIEW)

$\overline{OE1}$	1	56	$\overline{OE4}$
1B1	2	55	8B1
1B2	3	54	8B2
GND	4	53	GND
1B3	5	52	8B3
1B4	6	51	8B4
$V_{CC}$	7	50	$V_{CC}$
1A	8	49	8A
2B1	9	48	7B1
2B2	10	47	7B2
GND	11	46	GND
2B3	12	45	7B3
2B4	13	44	7B4
2A	14	43	7A
3A	15	42	6A
3B1	16	41	6B1
3B2	17	40	6B2
GND	18	39	GND
3B3	19	38	6B3
3B4	20	37	6B4
4A	21	36	5A
$V_{CC}$	22	35	$V_{CC}$
4B1	23	34	5B1
4B2	24	33	5B2
GND	25	32	GND
4B3	26	31	5B3
4B4	27	30	5B4
$\overline{OE2}$	28	29	$\overline{OE3}$

A-TO-B FUNCTION TABLE

INPUTS		OUTPUT
$\overline{OE}$	A	$B_n$
L	H	H
L	L	L
H	X	Z

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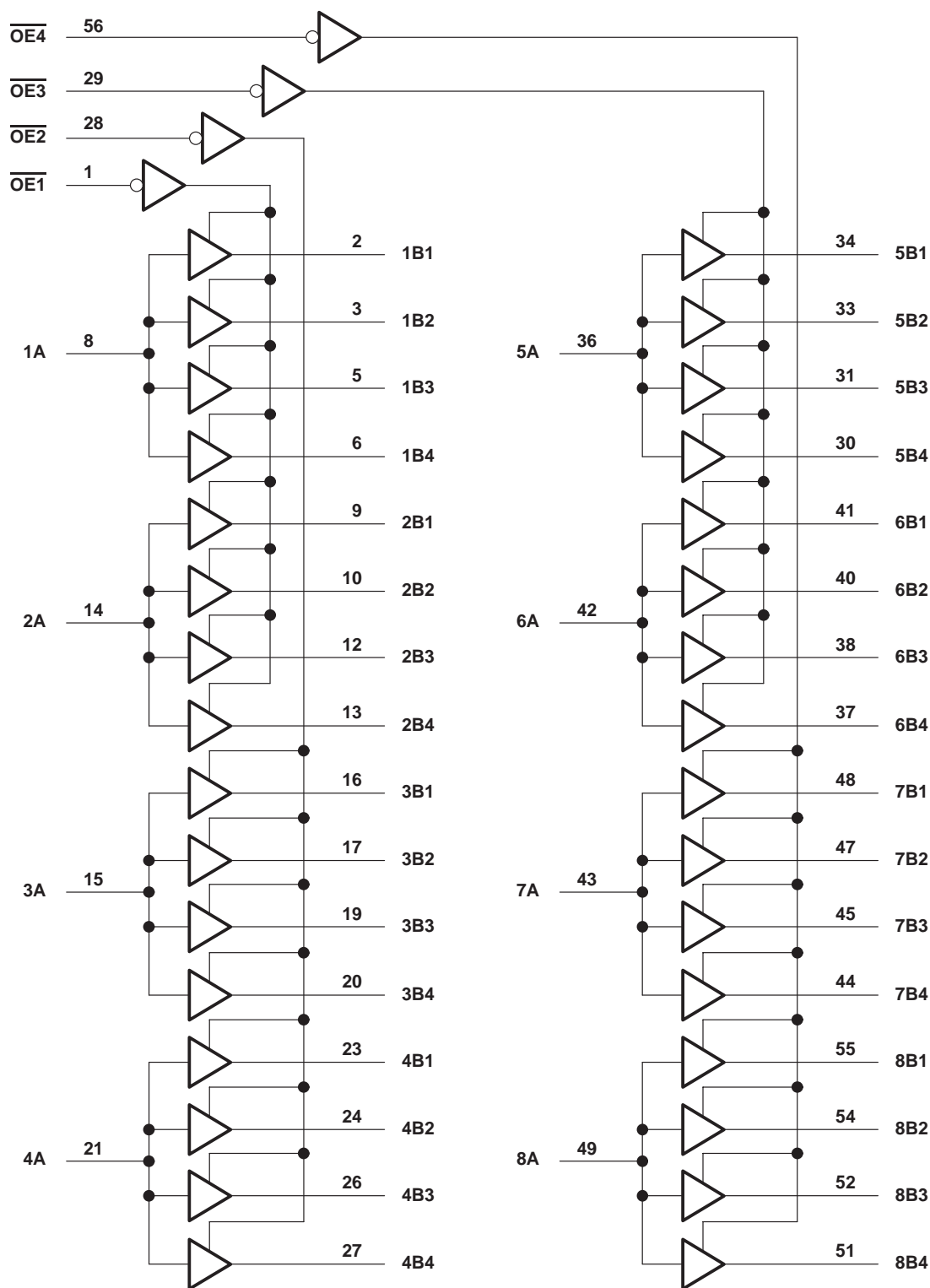
# SN74ALVCH162344

## 1-BIT TO 4-BIT ADDRESS DRIVER

### WITH 3-STATE OUTPUTS

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#### logic diagram (positive logic)



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### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Supply voltage range, $V_{CC}$	–0.5 V to 4.6 V
Input voltage range, $V_I$ (see Note 1)	–0.5 V to 4.6 V
Output voltage range, $V_O$ (see Notes 1 and 2)	–0.5 V to $V_{CC} + 0.5$ V
Input clamp current, $I_{IK}$ ( $V_I < 0$ )	–50 mA
Output clamp current, $I_{OK}$ ( $V_O < 0$ )	–50 mA
Continuous output current, $I_O$	±50 mA
Continuous current through each $V_{CC}$ or GND	±100 mA
Package thermal impedance, $\theta_{JA}$ (see Note 3): DGG package	81°C/W
DGV package	86°C/W
DL package	74°C/W
Storage temperature range, $T_{stg}$	–65°C to 150°C

<sup>†</sup> Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.  
2. This value is limited to 4.6 V maximum.  
3. The package thermal impedance is calculated in accordance with JESD 51.

### recommended operating conditions (see Note 4)

		MIN	MAX	UNIT
$V_{CC}$	Supply voltage	1.65	3.6	V
$V_{IH}$	High-level input voltage	$V_{CC} = 1.65$ V to 1.95 V	$0.65 \times V_{CC}$	V
		$V_{CC} = 2.3$ V to 2.7 V	1.7	
		$V_{CC} = 2.7$ V to 3.6 V	2	
$V_{IL}$	Low-level input voltage	$V_{CC} = 1.65$ V to 1.95 V	$0.35 \times V_{CC}$	V
		$V_{CC} = 2.3$ V to 2.7 V	0.7	
		$V_{CC} = 2.7$ V to 3.6 V	0.8	
$V_I$	Input voltage	0	$V_{CC}$	V
$V_O$	Output voltage	0	$V_{CC}$	V
$I_{OH}$	High-level output current	$V_{CC} = 1.65$ V	–2	mA
		$V_{CC} = 2.3$ V	–6	
		$V_{CC} = 2.7$ V	–8	
		$V_{CC} = 3$ V	–12	
$I_{OL}$	Low-level output current	$V_{CC} = 1.65$ V	2	mA
		$V_{CC} = 2.3$ V	6	
		$V_{CC} = 2.7$ V	8	
		$V_{CC} = 3$ V	12	
$\Delta t/\Delta v$	Input transition rise or fall rate		10	ns/V
$T_A$	Operating free-air temperature	–40	85	°C

NOTE 4: All unused control inputs of the device must be held at  $V_{CC}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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**electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)**

PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP†	MAX	UNIT
V <sub>OH</sub>	I <sub>OH</sub> = –100 µA	1.65 V to 3.6 V	V <sub>CC</sub> –0.2			V
	I <sub>OH</sub> = –2 mA	1.65 V	1.2			
	I <sub>OH</sub> = –4 mA	2.3 V	1.9			
	I <sub>OH</sub> = –6 mA	2.3 V	1.7			
		3 V	2.4			
	I <sub>OH</sub> = –8 mA	2.7 V	2			
	I <sub>OH</sub> = –12 mA	3 V	2			
V <sub>OL</sub>	I <sub>OL</sub> = 100 µA	1.65 V to 3.6 V	0.2			V
	I <sub>OL</sub> = 2 mA	1.65 V	0.45			
	I <sub>OL</sub> = 4 mA	2.3 V	0.4			
	I <sub>OL</sub> = 6 mA	2.3 V	0.55			
		3 V	0.55			
	I <sub>OL</sub> = 8 mA	2.7 V	0.6			
	I <sub>OL</sub> = 12 mA	3 V	0.8			
I <sub>I</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND	3.6 V	±5			µA
I <sub>I</sub> (hold)	V <sub>I</sub> = 0.58 V	1.65 V	25			µA
	V <sub>I</sub> = 1.07 V	1.65 V	–25			
	V <sub>I</sub> = 0.7 V	2.3 V	45			
	V <sub>I</sub> = 1.7 V	2.3 V	–45			
	V <sub>I</sub> = 0.8 V	3 V	75			
	V <sub>I</sub> = 2 V	3 V	–75			
	V <sub>I</sub> = 0 to 3.6 V‡	3.6 V	±500			
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	3.6 V	±10			µA
I <sub>CC</sub>	V <sub>I</sub> = V <sub>CC</sub> or GND, I <sub>O</sub> = 0	3.6 V	40			µA
ΔI <sub>CC</sub>	One input at V <sub>CC</sub> – 0.6 V, Other inputs at V <sub>CC</sub> or GND	3 V to 3.6 V	750			µA
C <sub>i</sub>	Control inputs	3.3 V	2.5			pF
	Data inputs		3.5			
C <sub>O</sub>	Outputs	3.3 V	4			pF

† All typical values are at V<sub>CC</sub> = 3.3 V, T<sub>A</sub> = 25°C.

‡ This is the bus-hold maximum dynamic current. It is the minimum overdrive current required to switch the input from one state to another.

**switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figures 1 through 3)**

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A	B	§	1	4.9	5.1		1.4	4.4	ns
t <sub>en</sub>	$\overline{\text{OE}}$	B	§	1	6.4	6.6		1.2	5.7	ns
t <sub>dis</sub>	$\overline{\text{OE}}$	B	§	1	5.4	4.7		1.2	4.5	ns
t <sub>sk(o)</sub> ¶								0.35		ns
t <sub>sk(o)</sub> #								0.5		ns

§ This information was not available at the time of publication.

¶ Skew between outputs of the same bank and same package (same transition)

# Skew between outputs of all banks of same package (A1–A8 tied together)

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## 1-BIT TO 4-BIT ADDRESS DRIVER

### WITH 3-STATE OUTPUTS

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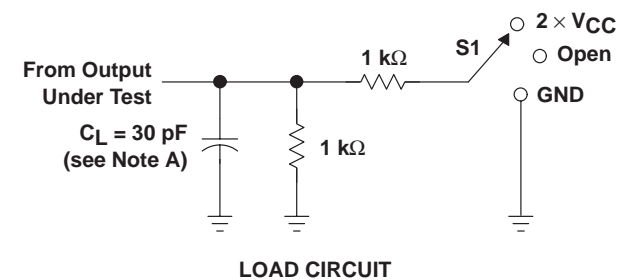
operating characteristics,  $T_A = 25^\circ\text{C}$

PARAMETER		TEST CONDITIONS	$V_{CC} = 1.8\text{ V}$	$V_{CC} = 2.5\text{ V}$	$V_{CC} = 3.3\text{ V}$	UNIT
			TYP	TYP	TYP	
$C_{pd}$ Power dissipation capacitance	Outputs enabled	$C_L = 0, f = 10\text{ MHz}$	†	68	82	pF
	Outputs disabled		†	12	14	

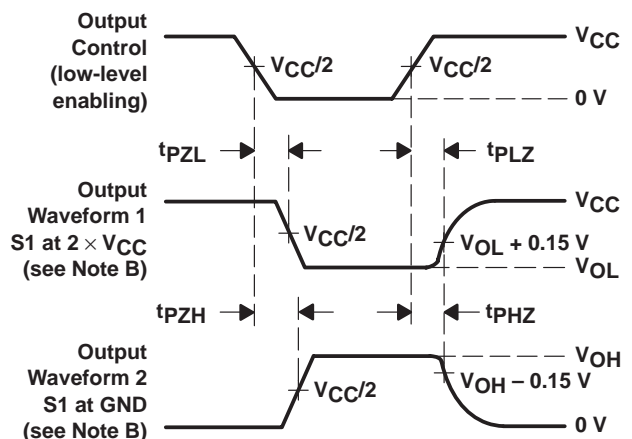
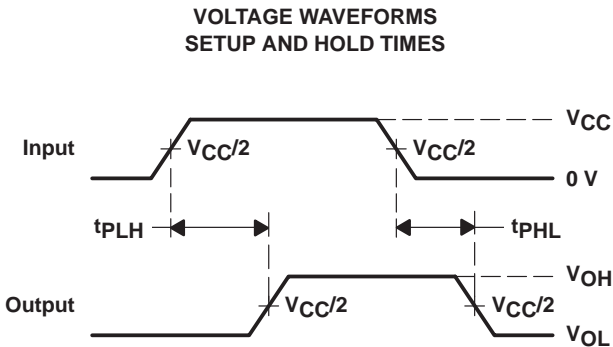
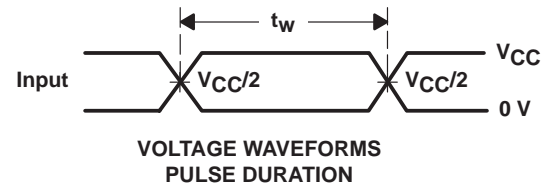
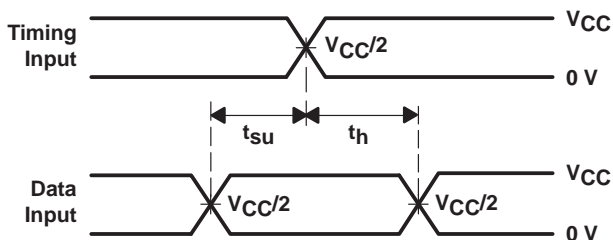
† This information was not available at the time of publication.

## PARAMETER MEASUREMENT INFORMATION

### $V_{CC} = 1.8\text{ V}$



TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	2 × $V_{CC}$
$t_{PHZ}/t_{PHZ}$	GND



- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics: PRR  $\leq 10\text{ MHz}$ ,  $Z_O = 50\ \Omega$ ,  $t_r \leq 2\text{ ns}$ ,  $t_f \leq 2\text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 1. Load Circuit and Voltage Waveforms

# SN74ALVCH162344

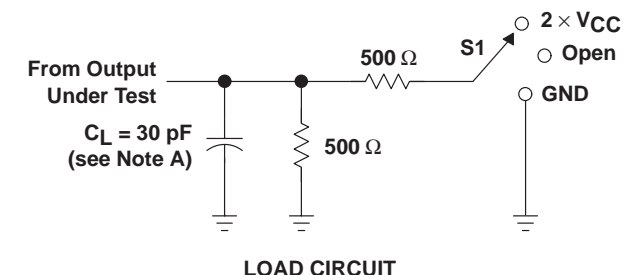
## 1-BIT TO 4-BIT ADDRESS DRIVER

### WITH 3-STATE OUTPUTS

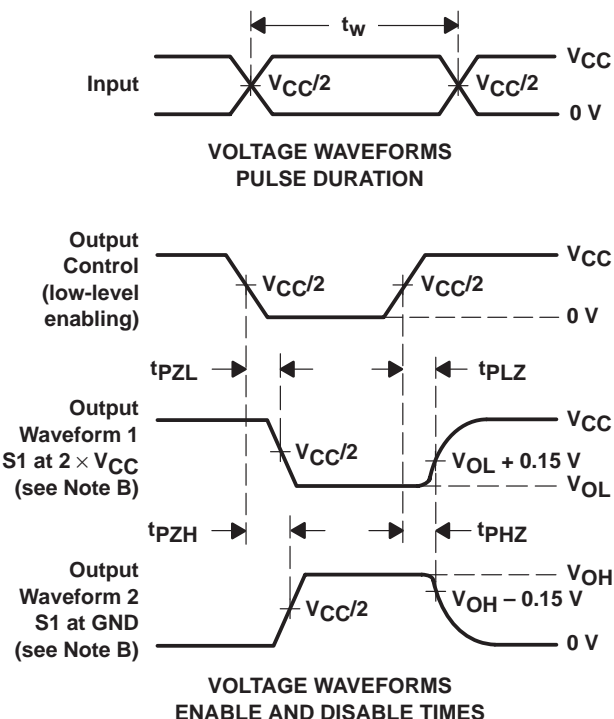
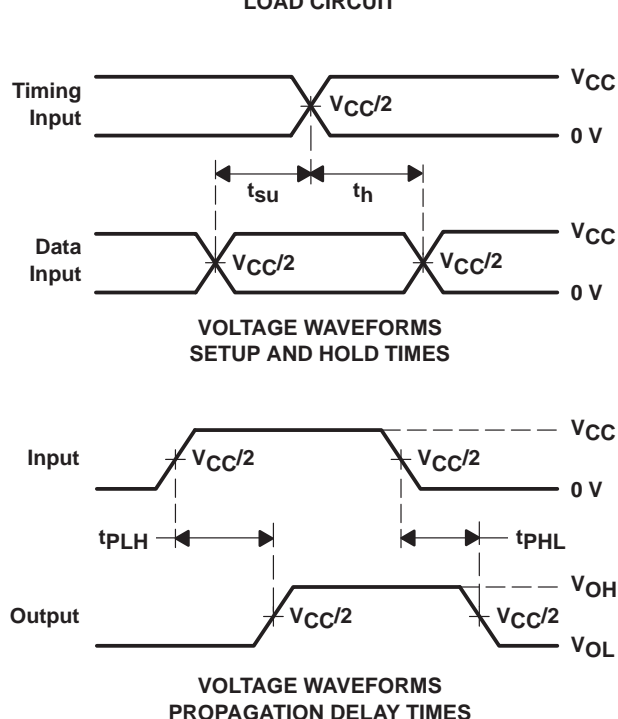
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#### PARAMETER MEASUREMENT INFORMATION

$$V_{CC} = 2.5 \text{ V} \pm 0.2 \text{ V}$$



TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	2 $\times V_{CC}$
$t_{PHZ}/t_{PZH}$	GND



- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2 \text{ ns}$ ,  $t_f \leq 2 \text{ ns}$ .
  - D. The outputs are measured one at a time with one transition per measurement.
  - E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - F.  $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 2. Load Circuit and Voltage Waveforms

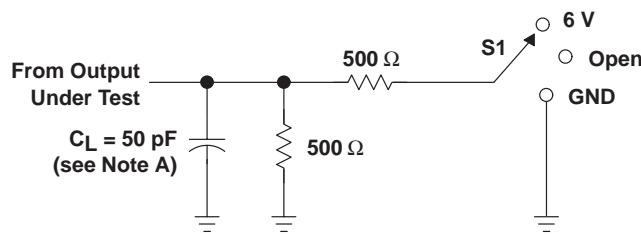
# SN74ALVCH162344

## 1-BIT TO 4-BIT ADDRESS DRIVER WITH 3-STATE OUTPUTS

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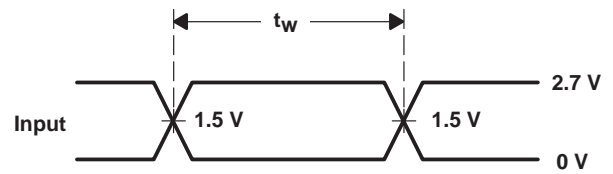
### PARAMETER MEASUREMENT INFORMATION

$V_{CC} = 2.7 \text{ V AND } 3.3 \text{ V} \pm 0.3 \text{ V}$

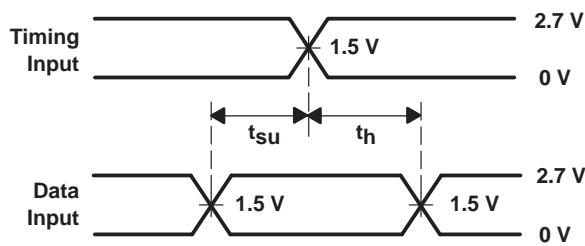


LOAD CIRCUIT

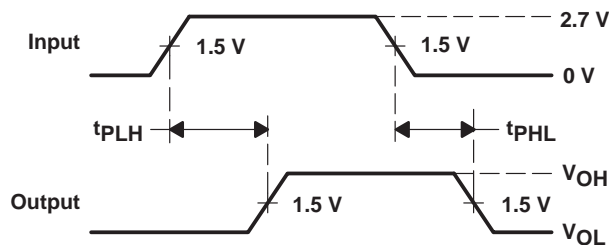
TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	6 V
$t_{PHZ}/t_{PZH}$	GND



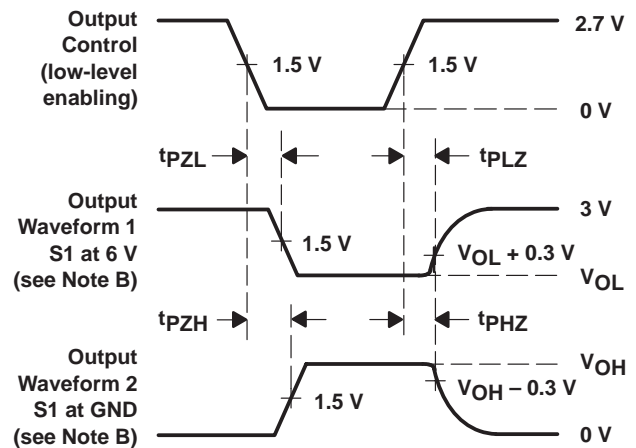
VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- NOTES:
- $C_L$  includes probe and jig capacitance.
  - Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2.5 \text{ ns}$ ,  $t_f \leq 2.5 \text{ ns}$ .
  - The outputs are measured one at a time with one transition per measurement.
  - $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
  - $t_{PZL}$  and  $t_{PZH}$  are the same as  $t_{en}$ .
  - $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .

Figure 3. Load Circuit and Voltage Waveforms

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